TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX125F,TC74LVX125FN,TC74LVX125FT

Quad Bus Buffer

The TC74LVX125F/ FN/ FT is a high-speed CMOS quad bus buffer fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation. This device is suitable for low-voltage and battery operated systems.

This device requires the 3-state control input $\overline{G}$ to be set high to place the output into the high-impedance.

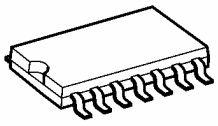
An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High-speed: t_{pd} = 4.4 ns (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- Input voltage level: V_{IL} = 0.8 V (max) (V_{CC} = 3 V)
  V_{IH} = 2.0 V (min) (V_{CC} = 3 V)
- Power-down protection is provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: V_{OLP} = 0.5 V (max)
- Pin and function compatible with 74HC125

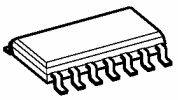
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74LVX125F



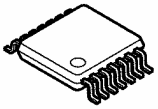
SOP14-P-300-1.27A

TC74LVX125FN



SOL14-P-150-1.27

TC74LVX125FT

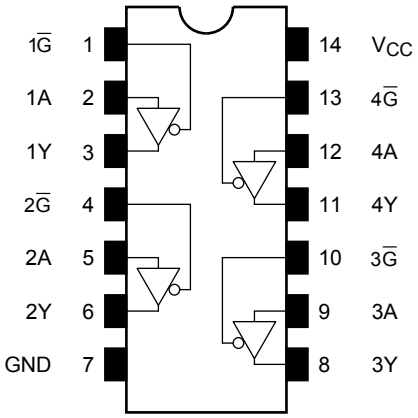


TSSOP14-P-0044-0.65A

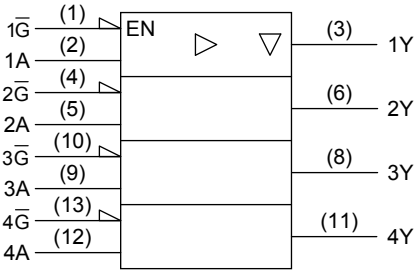
Weight

SOP14-P-300-1.27A	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputs
$\overline{G}$	A	Y
H	X	Z
L	L	L
L	H	H

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
Input voltage	H-level	V_{IH}	—		2.0	1.5	—	—	1.5	—	V
					3.0	2.0	—	—	2.0	—	
					3.6	2.4	—	—	2.4	—	
	L-level	V_{IL}	—		2.0	—	—	0.5	—	0.5	
					3.0	—	—	0.8	—	0.8	
					3.6	—	—	0.8	—	0.8	
Output voltage	H-level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				I_{OH} = −50 μA	3.0	2.9	3.0	—	2.9	—	
				I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
	L-level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA	3.0	—	0	0.1	—	0.1	
				I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
3-state output Off-state current		I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		3.6	—	—	±0.25	—	±2.5	μA
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		3.6	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH}	—	2.7	15	—	5.8	10.1	1.0	13.5	ns
				50	—	8.3	13.6	1.0	17.0	
	t_{pHL}		3.3 ± 0.3	15	—	4.4	6.2	1.0	8.5	
				50	—	6.9	9.7	1.0	12.0	
Output enable time	t_{pZL}	R_L = 1 kΩ	2.7	15	—	5.3	9.3	1.0	12.5	ns
				50	—	7.8	12.8	1.0	16.0	
	t_{pZH}		3.3 ± 0.3	15	—	4.0	5.6	1.0	7.5	
				50	—	6.5	9.1	1.0	11.0	
Output disable time	t_{pLZ}	R_L = 1 kΩ	2.7	50	—	10.0	15.7	1.0	19.0	ns
	t_{pHZ}		3.3 ± 0.3	50	—	8.3	11.2	1.0	13.0	
Output to output skew	t_{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t_{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C_{IN}	(Note 2)			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note 3)			—	14	—	—	—	pF

Note 1: Parameter guaranteed by design.
($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

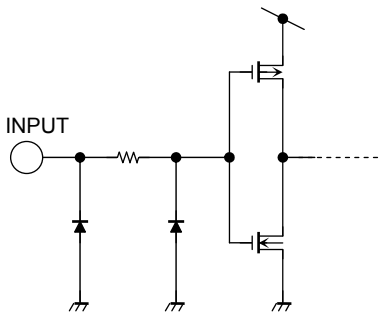
Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per bit)

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

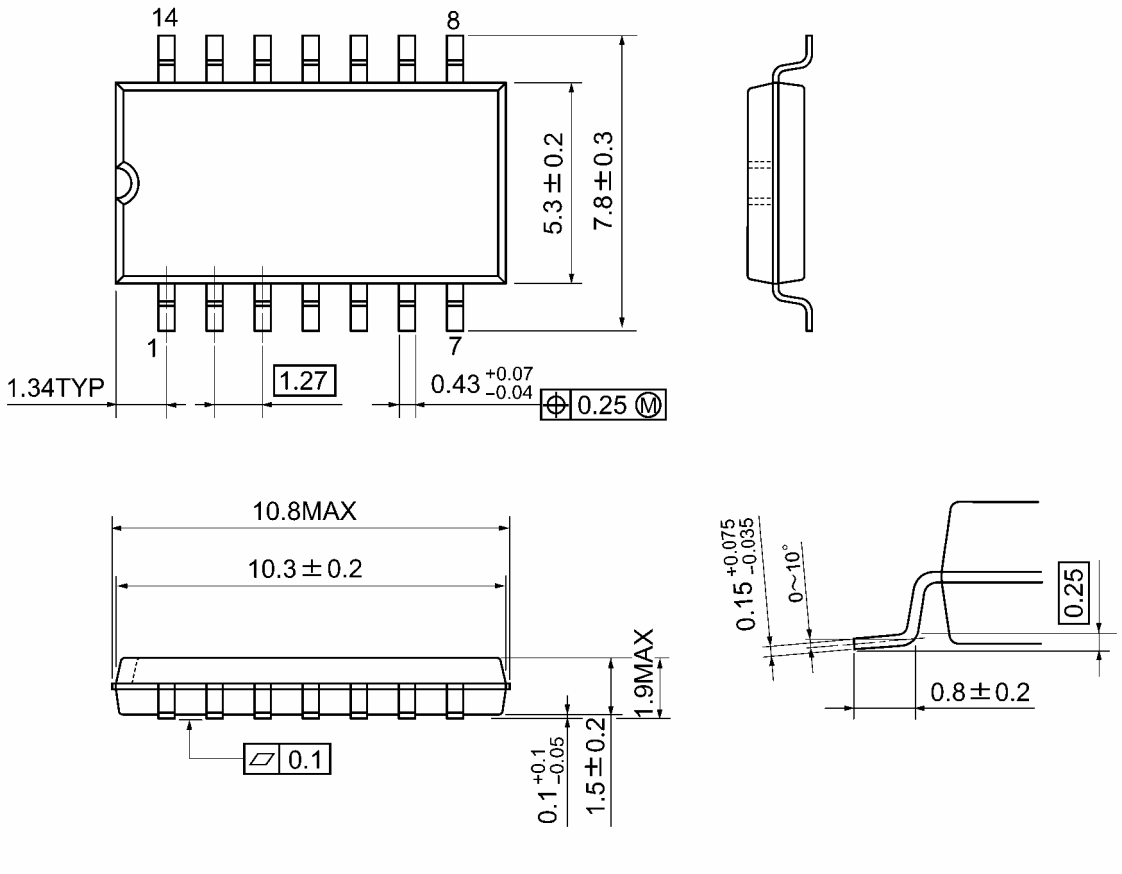
Characteristics		Symbol	Test Condition	V_{CC} (V)	Typ.	Limit	Unit
Quiet output maximum dynamic	V_{OL}	V_{OLP}	—	3.3	0.3	0.5	V
Quiet output minimum dynamic	V_{OL}	V_{OLV}	—	3.3	−0.3	−0.5	V
Minimum high level dynamic input voltage	V_{IH}	V_{IHD}	—	3.3	—	2.0	V
Maximum low level dynamic input voltage	V_{IL}	V_{ILD}	—	3.3	—	0.8	V

Input Equivalent Circuit



Package Dimensions

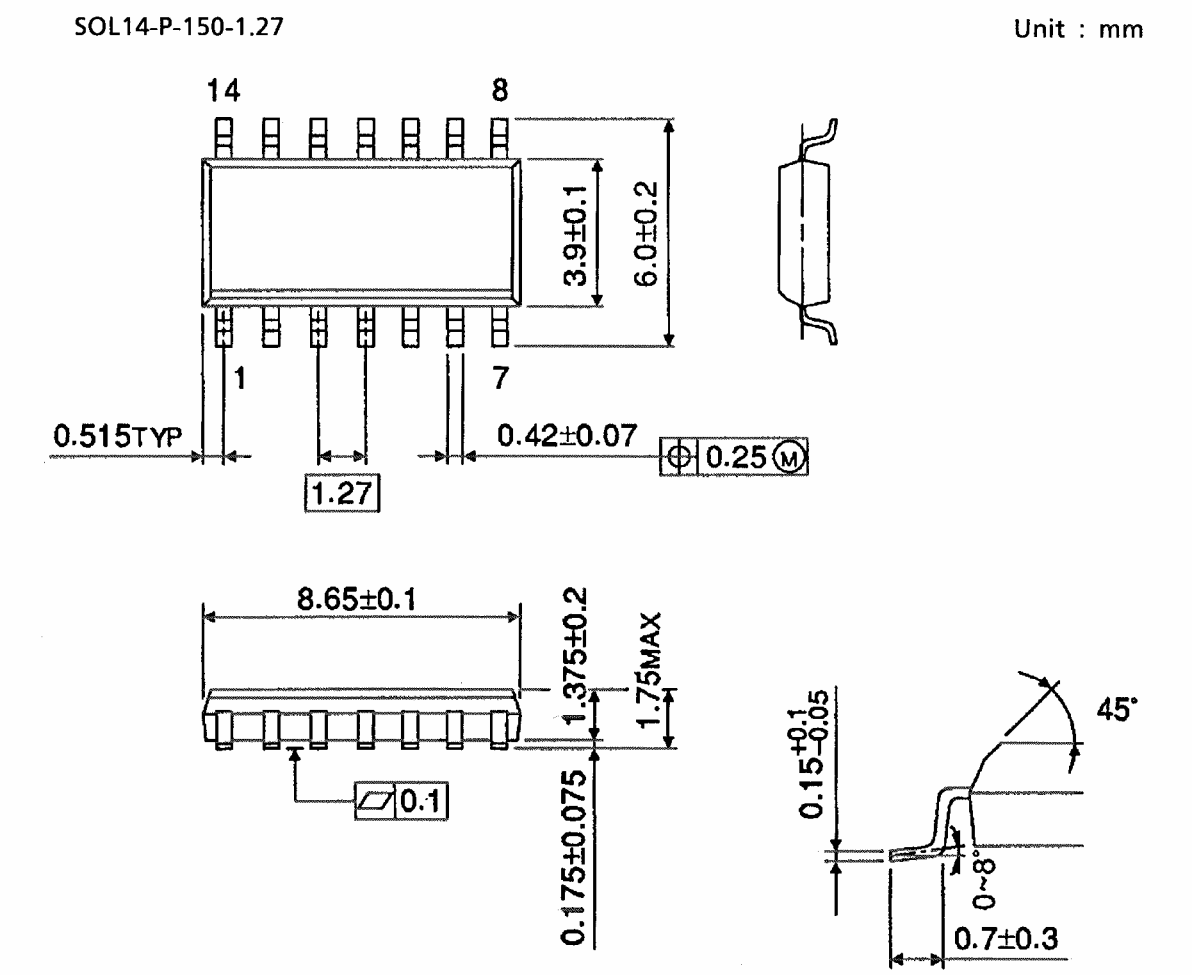
SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit : mm

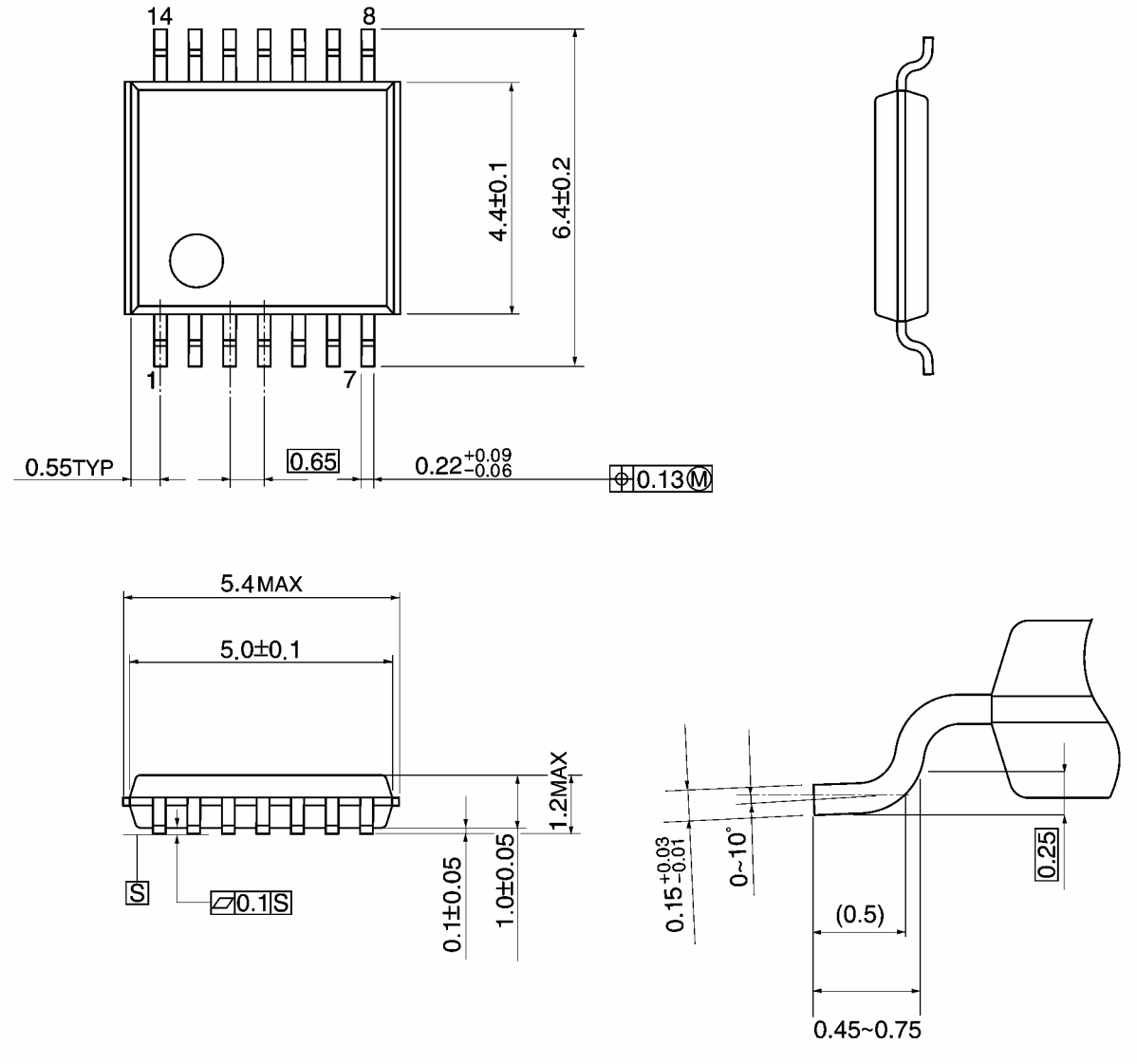


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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